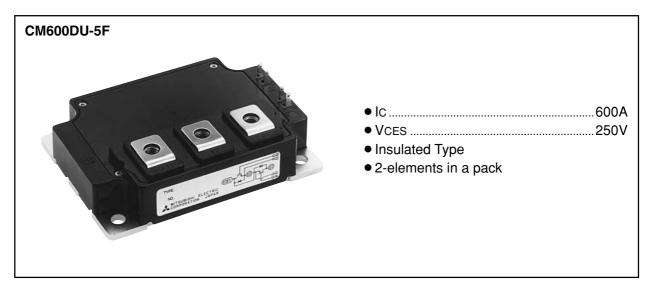
MITSUBISHI IGBT MODULES

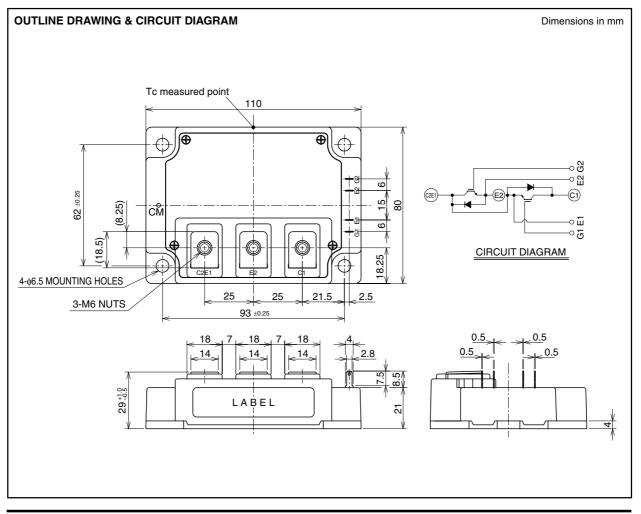
CM600DU-5F

HIGH POWER SWITCHING USE



APPLICATION

AC moter controll of forklift (battery power source)





CM600DU-5F

HIGH POWER SWITCHING USE

| Symbol | Parameter | Conditions | | Ratings | Unit |
|------------------|-------------------------------|--|---------|------------|--------|
| VCES | Collector-emitter voltage | G-E Short | | 250 | V |
| VGES | Gate-emitter voltage | C-E Short | | ±20 | V |
| lc | Collector current | Tc = 25°C | | 600 | A |
| IC(rms) | | | | 350 | A(rms) |
| Ісм | | Pulse (N | Note 2) | 1200 | A |
| IE (Note 1) | Emitter current | Tc = 25°C | | 600 | Α |
| IE(rms) (Note 1) | | | | 350 | A(rms) |
| IEM (Note 1) | | Pulse (M | Note 2) | 1200 | A |
| PC (Note 3) | Maximum collector dissipation | $TC = 25^{\circ}C$ | | 1100 | W |
| Tj | Junction temperature | | | -40 ~ +150 | °C |
| Tstg | Storage temperature | | | -40 ~ +125 | °C |
| Viso | Isolation voltage | Terminals to base plate, f = 60Hz, AC 1 minute | | 2500 | Vrms |
| _ | Torque strength | Main terminals M6 screw | | 3.5 ~ 4.5 | N۰m |
| | | Mounting M6 screw | | 3.5 ~ 4.5 | N•m |
| _ | Weight | Typical value | | 580 | g |

MAXIMUM RATINGS (Tj = 25°C, unless otherwise specified)

ELECTRICAL CHARACTERISTICS (Tj = 25°C, unless otherwise specified)

| | | Test conditions | | Limits | | | |
|--------------|--------------------------------------|---|-------|--------|------|------|------|
| Symbol | Parameter | | | Min. | Тур. | Max. | Unit |
| ICES | Collector cutoff current | VCE = VCES, VGE = 0V | | _ | | 1 | mA |
| VGE(th) | Gate-emitter threshold voltage | IC = 60mA, VCE = 10V | | 3.0 | 4.0 | 5.0 | v |
| IGES | Gate leakage current | ±VGE = VGES, VCE = 0V | | | _ | 0.5 | μA |
| VCE(sat) | Collector-emitter saturation voltage | Tj = | 25°C | _ | 1.2 | 1.7 | - V |
| | | $IC = 600A, VGE = 10V$ $T_{j} =$ | 125°C | — | 1.1 | — | |
| Cies | Input capacitance | VCE = 10V | | — | — | 170 | nF |
| Coes | Output capacitance | | | — | — | 11 | |
| Cres | Reverse transfer capacitance | VGE = 0V | | _ | — | 5.7 | |
| QG | Total gate charge | Vcc = 100V, Ic = 600A, VGE = 10V | | _ | 2200 | — | nC |
| td(on) | Turn-on delay time | | | _ | _ | 850 | |
| tr | Turn-on rise time | Vcc = 100V, Ic = 600A VGE = $\pm 10V$ RG = 4.2 Ω , Inductive load IE = 600A | | _ | _ | 600 | ns |
| td(off) | Turn-off delay time | | | _ | — | 1100 | |
| tr | Turn-off fall time | | | _ | — | 500 | |
| trr (Note 1) | Reverse recovery time | | | _ | _ | 300 | ns |
| Qrr (Note 1) | Reverse recovery charge | | | _ | 20.0 | _ | μC |
| VEC(Note 1) | Emitter-collector voltage | IE = 600A, VGE = 0V | | _ | — | 2 | V |
| Rth(j-c)Q | | IGBT part (1/2 module) | | _ | _ | 0.11 | K/W |
| Rth(j-c)R | Thermal resistance ^{*1} | FWDi part (1/2 module) | | _ | _ | 0.20 | |
| Rth(c-f) | Contact thermal resistance | Case to heat sink, Thermal compound applied ^{*2} (1/2 module) | | | 0.02 | — | |
| Rth(j-c')Q | Thermal resistance*3 | Case temperature measured point is just under the chips | | _ | _ | 0.05 | |

Note 1. IE, VEC, trr, Qrr & die/dt represent characteristics of the anti-parallel, emitter-collector free-wheel diode (FWDi).

2. Pulse width and repetition rate should be such that the device junction temperature (Tj) does not exceed Tjmax rating.

3. Junction temperature (Tj) should not increase beyond 150°C.

4. Pulse width and repetition rate should be such as to cause negligible temperature rise. *1 : Case temperature (Tc) measured point is indicated in OUTLINE DRAWING. *2 : Typical value is measured by using thermally conductive grease of $\lambda = 0.9[W/(m \cdot K)]$. *3 : If you use this value, Rth(f-a) should be measured just under the chips.

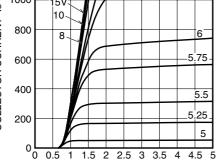


CM600DU-5F

HIGH POWER SWITCHING USE

(TYPICAL) 1200 6.5 $T_i = 25^{\circ}C$ VGE = IC (A) 1000 5V 10 COLLECTOR CURRENT 800 8 600

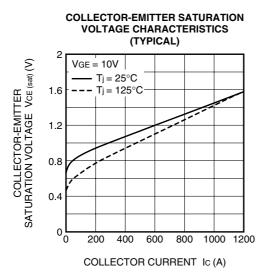
PERFORMANCE CURVES

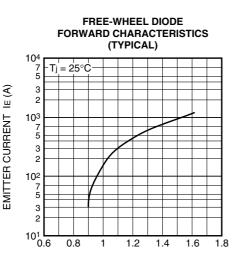


OUTPUT CHARACTERISTICS

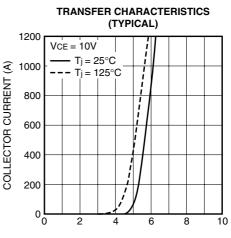
6.25

COLLECTOR-EMITTER VOLTAGE VCE (V)



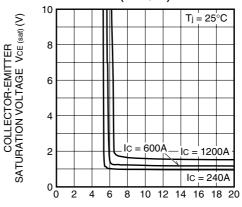


EMITTER-COLLECTOR VOLTAGE VEC (V)



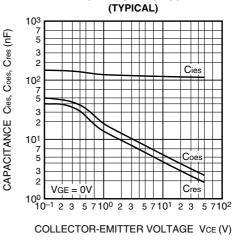
GATE-EMITTER VOLTAGE VGE (V)





GATE-EMITTER VOLTAGE VGE (V)

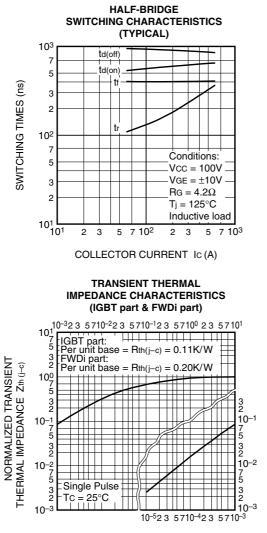
CAPACITANCE-VCE **CHARACTERISTICS**



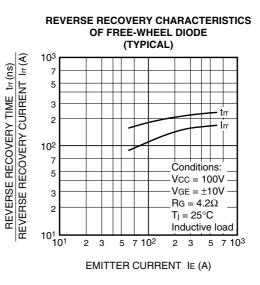
MITSUBISHI ELECTRIC

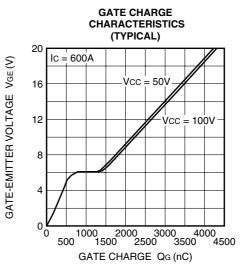
CM600DU-5F

HIGH POWER SWITCHING USE



TIME (s)







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